

RELEASE Ø DATA SHEET





GRF2070 Ultra-Low Noise Amplifier 0.1 to 1.5 GHz

FEATURES

- Excellent NF Performance
- High Gain
- Outstanding Linearity
- Flexible Bias Voltage and Current
- Compact 2.0 x 2.0 mm DFN-8 Package
- Process: GaAs pHEMT

Reference: 5 V / 0.9 GHz / 70 mA

• Gain: 21 dB

• OIP3: 39 dBm

• OP1dB: 20 dBm

• Evaluation Board Noise Figure: 0.4 dB

APPLICATIONS

- Cellular Infrastructure
- Small Cells and Cellular Repeaters
- Distributed Antenna Systems

DESCRIPTION

The GRF2070 is a broadband, linear, ultra-low noise amplifier designed for small cell, wireless infrastructure, and other high performance RF applications requiring ultra-low NF, high gain, and linearity.

This device is a member of a family of pin-compatible, ultra-low noise devices which cover a wide range of frequency bands with industry leading NF and gain:

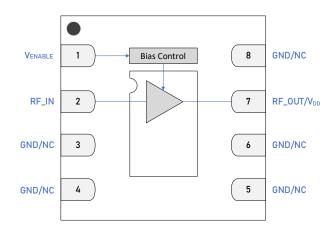
<u>GRF2070</u>: 0.1 to 1.5 GHz <u>GRF2071</u>: 0.7 to 2.7 GHz

GRF2072: 1.5 to 3.8 GHz GRF2073: 2.0 to 6.0 GHz

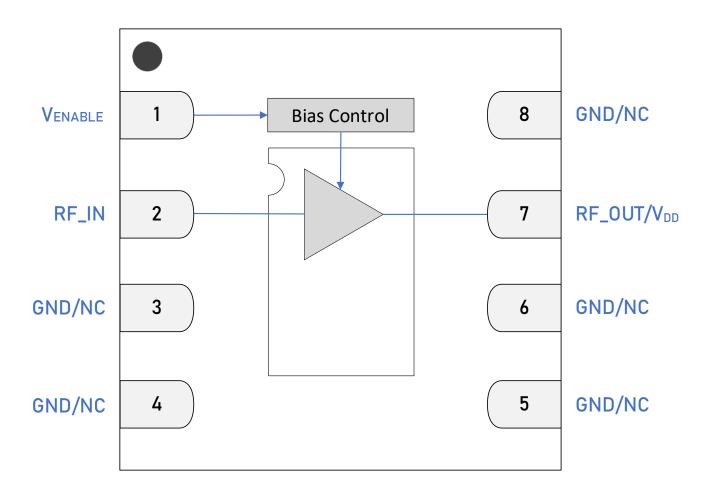
GRF2074: 1.0 to 6.0 GHz (Next-gen Process)

Please consult with the GRF applications engineering team for application notes and custom tuning/evaluation board data. De-embedded S-parameters with noise parameters are available on the website.

B BLOCK DIAGRAM







2.0 x 2.0 mm DFN-8 Pin Out (Top View)







Pin Assignments

Pin	Name	Description	Note
1	Venable	Enable Voltage Input	V_{ENABLE} and series resistor set I_{DDQ} . $V_{\text{ENABLE}} \leq 0.2$ volts disables device.
2	RF_IN	RF Input	External match must provide DC block.
3, 4, 5, 6, 8	GND/NC	Ground or No Connect	No internal connection to die.
7	RF_Out/V _{DD}	RF Output	Provide device V _{DD} via external bias inductor.
PKG BASE	GND	Ground	Provides DC and RF ground for LNA, as well as thermal heat sink. Recommend multiple 8 mil vias beneath the package for optimal RF and thermal performance. Refer to evaluation board top layer graphic on schematic page.



Absolute Ratings

Parameter	Symbol	Min.	Max.	Unit
Supply Voltage	V_{DD}	0	6	V
RF Input Power (Load VSWR < 2:1, V _{DD} = 5 V)	P _{IN MAX}		23	dBm
Operating Temperature (Package Heat Sink)	TPKG HEAT SINK	-40	105	°C
Maximum Channel Temperature (MTTF >10 ⁶ Hours)	Тмах		170	°C
Maximum Dissipated Power	Pdiss max		500	mW
Electrostatic Discharge				
Charged Device Model	CDM	1500		V
Human Body Model	НВМ	500		V
Storage				
Storage Temperature	T _{STG}	-65	150	°C
Moisture Sensitivity Level	MSL		1	



Caution! ESD Sensitive Device.

Exceeding Absolute Maximum Rating conditions may cause permanent damage.

Note: For additional information, please refer to Package Manufacturing Information | Guerrilla RF (guerrilla-rf.com)



All Guerrilla RF products are provided in RoHS compliant lead (Pb)-free packaging. For additional information, please refer to the ROHS Compliance | Guerrilla RF (guerrilla-rf.com)



Recommended Operating Conditions

		Specification					
Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition	
Supply Voltage	V _{DD}	0	5	6	V		
Operating Temperature (Package Heat Sink)	TPKG HEAT SINK	-40		105	°C		
RF Frequency Range	F _{RF}	0.1	0.9	1.5	GHz	Typical Application Schematic with external matching components (note 1 & 2).	

Note 1: Operation outside this range is possible, but with degraded performance of some parameters.

Note 2: Contact the Guerrilla RF Applications team for guidance on optimizing the tuning of the device for alternative bands.



Nominal Operating Parameters – General

The following conditions apply unless noted otherwise: Typical Application Schematic using the 0.1 to 1.5 GHz tuning set, M3 = 900 Ω , V_{DD} = 5 V, V_{ENABLE} = 5 V, I_{DD} = 70 mA, F_{TEST} = 0.9 GHz, T_{PKG HEAT SINK} = 25 °C. Evaluation board losses are included within the specifications.

		Specification				
Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Supply Current	I _{DD}		70		mA	Adjustable for optimal IP3.
Enable Current	I _{ENABLE}		3.5		mA	
Switching Rise Time	T _{RISE}		1800		ns	
Switching Fall Time	T _{FALL}		900		ns	

Thermal Data

Thermal Resistance: (Infrared Scan)	Θις		60		°C/W	On standard evaluation board (note 3).
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Note 3: MTTF > 10^6 hours for T_{CHANNEL} ≤ 170 °C.



Nominal Operating Parameters – RF

The following conditions apply unless noted otherwise: Typical Application Schematic using the 0.1 to 1.5 GHz tuning set, M3 = 900 Ω , V_{DD} = 5 V, V_{ENABLE} = 5 V, I_{DD} = 70 mA, F_{TEST} = 0.9 GHz, T_{PKG} HEAT SINK = 25 °C. Evaluation board losses are included within the specifications.

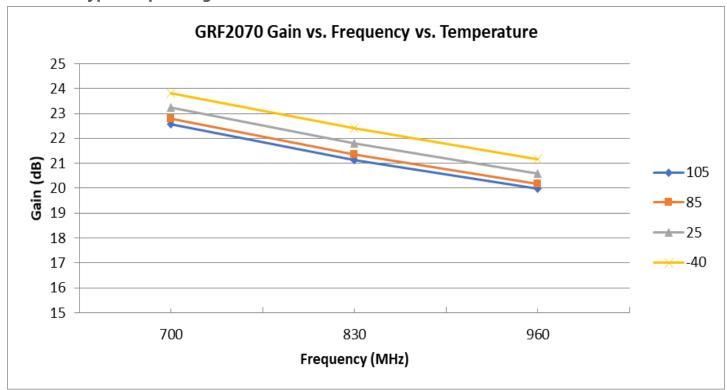
		Specification				
Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Gain	S21	20	21		dB	
Reverse Isolation	S12		-26		dB	F _{RF} : 0.7 to 0.96 GHz
Evaluation Board Noise Figure	NF		0.4	0.6	dB	Evaluation Board SMA to SMA
Output 3 rd Order Intercept	OIP3		39		dBm	+4 dBm P _{OUT} per tone at 2 MHz Spacing (899 and 901 MHz)
Output 1 dB Compression Power	OP1dB	18.6	20		dBm	

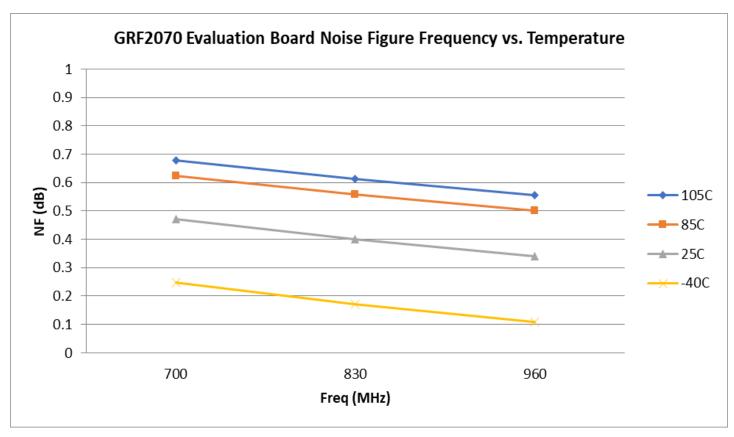
Typical Operating Curve Conditions

The following conditions apply unless noted otherwise: Typical Application Schematic using the 0.1 to 1.5 GHz tuning set, M3 = 900 Ω , V_{DD} = 5 V, V_{ENABLE} = 5 V, I_{DD} = 70 mA, F_{TEST} = 0.9 GHz, T_{PKG} HEAT SINK = 25 °C. Evaluation board losses are included within the plots.



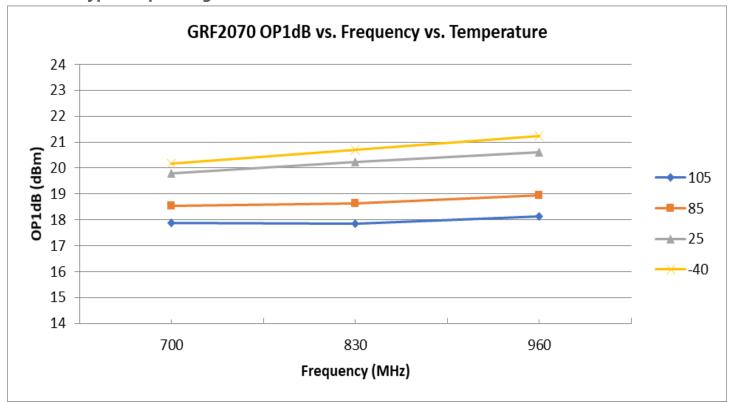
GRF2070 Typical Operating Curves

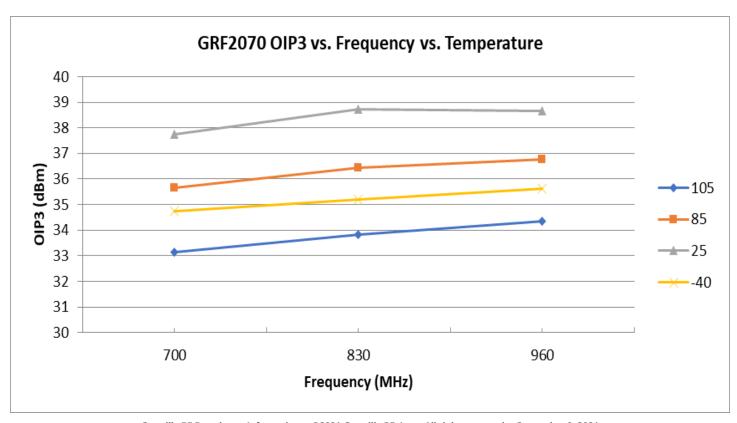






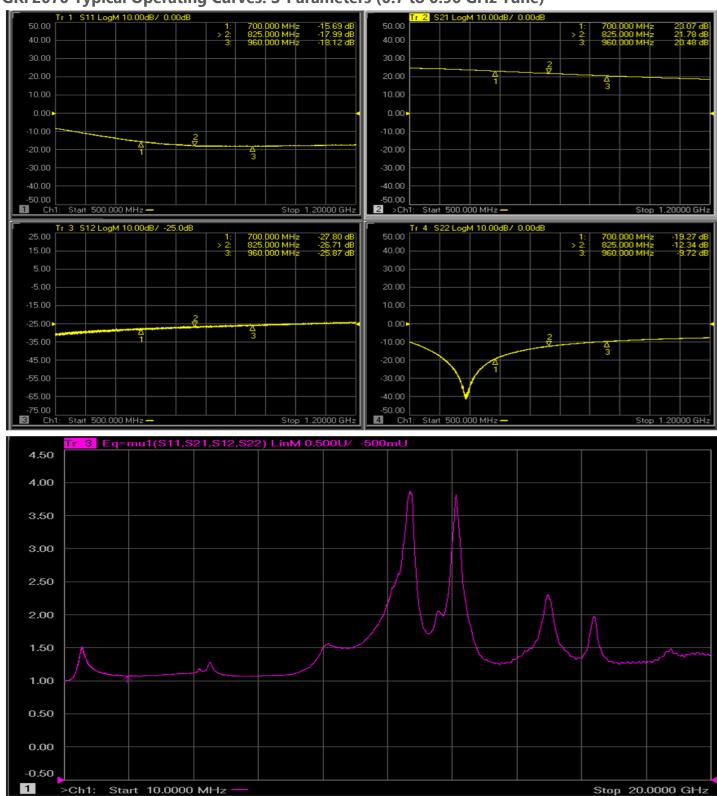
GRF2070 Typical Operating Curves





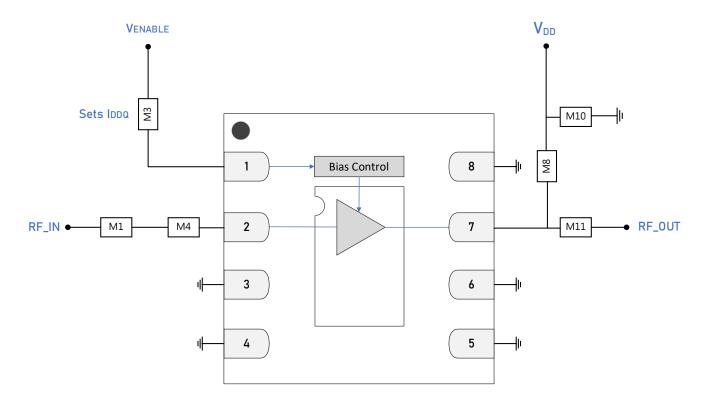


GRF2070 Typical Operating Curves: S-Parameters (0.7 to 0.96 GHz Tune)

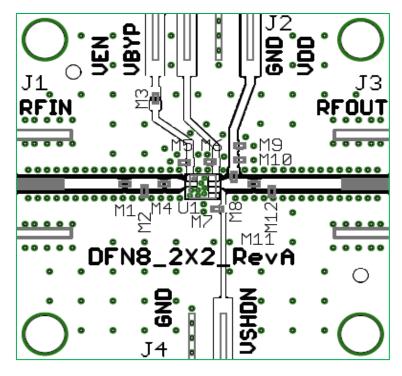


Note: Mu Factor ≥ 1.0 implies unconditional stability.





GRF2070 Standard Test Schematic



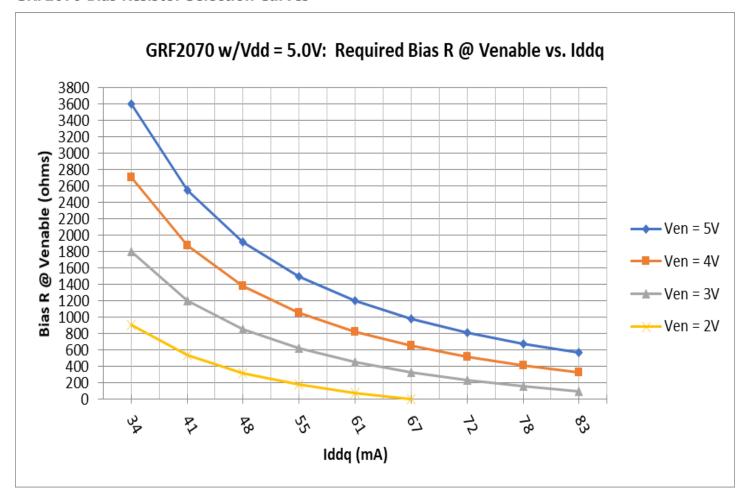
GRF2070 Evaluation Board Assembly Diagram



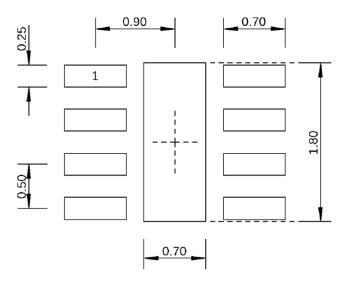
GRF2070 Evaluation Board Assembly Diagram Reference: 0.7 to 0.96 GHz Tune

Component	Туре	Manufacturer	Family	Value	Package Size	Substitution
M1	Resistor (Jumper)	Various		0 Ω	0402	ok
M3	Resistor	Various	5%	Sets I _{DDQ}	0402	ok
M4	Capacitor	Murata	GJM	47 pF	0402	ok
M8	Inductor	Murata	LQW	22 nH	0402	ok
M10	Capacitor	Murata	GRM	0.1 μF	0402	ok
M11	Capacitor	Murata	GRM	4.7 pF	0402	ok
Evaluation Board	DFN8_2x2_RevA					

GRF2070 Bias Resistor Selection Curves

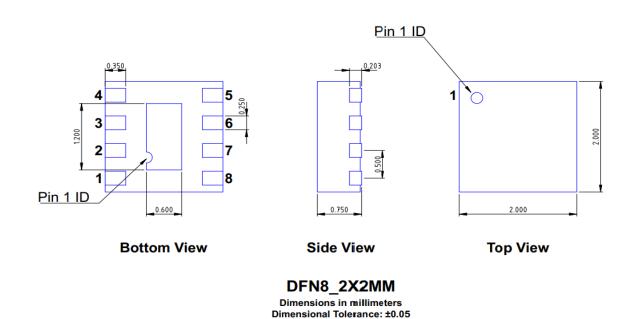






Dimensions in millimeters

2.0 x 2.0 mm DFN-8 Suggested PCB Footprint (Top View)



2.0 x 2.0 mm DFN-8 Package Dimensions



Package Marking Diagram



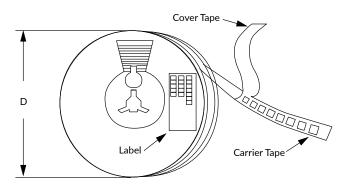
- Line 1: "Y" = YEAR (single digit). "WW" = WORK WEEK the Device was assembled.
- Line 2: "XXXX" = Device PART NUMBER.

Tape and Reel Information

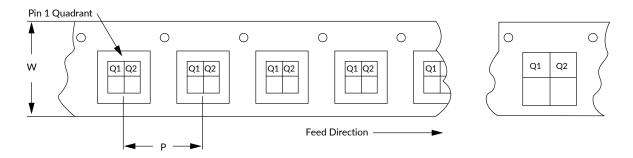
Guerrilla RF's tape and reel specification complies with Electronics Industries Association (EIA) standards for "Embossed Carrier Tape of Surface Mount Components for Automatic Handling" (reference EIA-481). See the following page for the Tape and Reel Specification and Device Package Information table, which includes units per reel.

Devices are loaded with pins down into the carrier pocket with protective cover tape and reeled onto a plastic reel. Each reel is packaged in a cardboard box. There are product labels on the reel, the protective ESD bag and the outside surface of the box.

For the Tape and Reel Reference Table, please refer to: Package Manufacturing Information | Guerrilla RF (guerrilla-rf.com)



Tape and Reel Packaging with Reel Diameter Noted (D)



Carrier Tape Width (W), Pitch (P), Feed Direction and Pin 1 Quadrant Information





Revision History

Revision Date	Description of Change
September 8, 2021	Converted format to new template.



Data Sheet Classifications

Data Sheet Status	Notes
Advance	S-parameter and NF data based on EM simulations for the fully packaged device using foundry-supplied transistor S-parameters. Linearity estimates based on device size, bias condition and experience with related devices.
Preliminary	All data based on evaluation board measurements taken within the Guerrilla RF Applications Lab. Any MIN/MAX limits represented within the data sheet are based solely on <i>estimated</i> part-to-part variations and process spreads. All parametric values are subject to change pending the collection of additional data.
Release Ø	All data based on measurements taken with <i>production-released</i> material. TYP values are based on a combination of ATE and bench-level measurements, with MIN/MAX limits defined using <i>modelled estimates</i> that account for part-to-part variations and expected process spreads. Although unlikely, future refinements to the TYP/MIN/MAX values may be in order as multiple lots are processed through the factory.
Release A-Z	All data based on measurements taken with production-released material derived from multiple lots which have been fabricated over an extended period of time. MIN/MAX limits may be refined over previous releases as more statistically significant data is collected to account for process spreads.

Information in this data sheet is specific to the Guerrilla RF, Inc. ("Guerrilla RF") product identified.

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